NSN 5962-00-443-9360

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View Online at https://aerobasegroup.com/nsn/5962-00-443-9360

Body Length:

Between 1.200 inches and 1.290 inches

Body Width:

Between 0.515 inches and 0.580 inches

Body Height:

Between 0.050 inches and 0.230 inches

Maximum Power Dissipation Rating:

650.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and bipolar and w/decoded output and w/enable and w/storage

and programmable and programmed

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Case Outline Source And Designator:

-0-015-aa joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-30.0 volts power source and 0.3 volts power source

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

92755-12793 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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